

N-channel 60 V 11.3 mΩ logic level MOSFET in LFPAK33

4 June 2013

Product data sheet

1. General description

Logic level enhancement mode N-channel MOSFET in LFPAK33 package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

2. Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources
- LFPAK33 package is footprint compatible with other 3.3mm types
- Qualified to 175 °C

3. Applications

- AC-to-DC converters
- Synchronous rectification
- DC-DC converters

4. Quick reference data

Table 1. C	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C	-	-	60	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	-	-	61	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	91	W
Tj	junction temperature		-55	-	175	°C
Static char	acteristics	1]
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; Fig. 12	-	9.35	11.3	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; <u>Fig. 12</u>	-	11	13.1	mΩ
Dynamic cl	haracteristics	· · · · · ·				
Q _{GD}	gate-drain charge	V_{GS} = 4.5 V; I_D = 15 A; V_{DS} = 30 V; T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.1	-	nC

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D
2	S	source		
3	S	source		G-UT4
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Ordering information

Fable 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PSMN011-60ML	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN011-60ML	M11L60

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

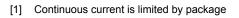
Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C	-	60	V
V _{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	-	61	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	-	43	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 4	-	242	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	91	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C

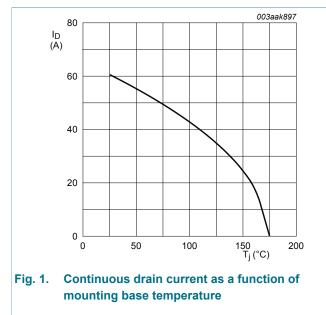
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PSMN011-60ML

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Symbol	Parameter	Conditions		Min	Мах	Unit
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-dra	in diode		- 1			
I _S	source current	T _{mb} = 25 °C	[1]	-	70	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	242	А
Avalanche	ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\label{eq:VGS} \begin{array}{l} V_{GS} \texttt{=} \ \texttt{10} \ V; \ T_{j(init)} \texttt{=} \ \texttt{25} \ ^\circ C; \ I_D \texttt{=} \ \texttt{61} \ A; \\ V_{sup} \texttt{\leq} \ \texttt{60} \ V; \ R_{GS} \texttt{=} \ \texttt{50} \ \Omega; \ unclamped; \\ \hline Fig. 3 \end{array}$		-	48.5	mJ





 $V_{GS} \ge 10V$

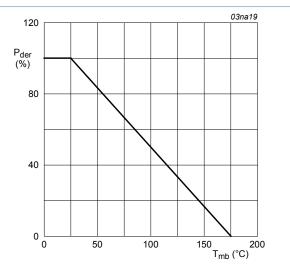
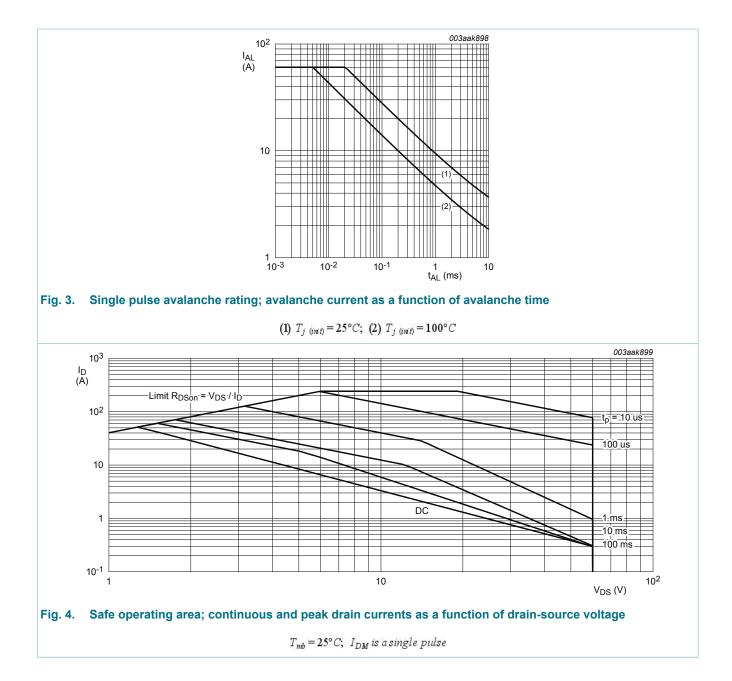


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

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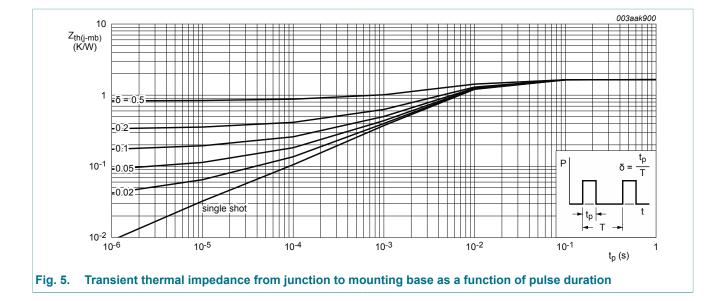
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9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	1.44	1.65	K/W

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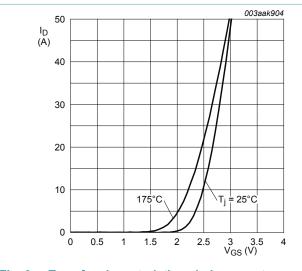


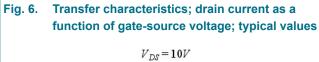
10. Characteristics

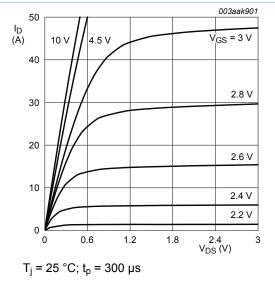
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	$50 \ \mu\text{A}; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}\text{C} \qquad 60 \qquad - \qquad -$ $50 \ \mu\text{A}; \ V_{GS} = 0 \ V; \ T_j = -55 \ ^{\circ}\text{C} \qquad 54 \qquad - \qquad -$ $m\text{A}; \ V_{DS} = V_{GS}; \ T_j = -55 \ ^{\circ}\text{C}; \qquad - \qquad - \qquad 2.45$ $m\text{A}; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}\text{C}; \qquad 1.3 \qquad 1.7 \qquad 2.15$ $m\text{A}; \ V_{DS} = V_{GS}; \ T_j = 175 \ ^{\circ}\text{C}; \qquad 0.5 \qquad - \qquad -$ $60 \ V; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}\text{C} \qquad - \qquad 0.03 \qquad 1$ $60 \ V; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}\text{C} \qquad - \qquad 0.03 \qquad 1$ $60 \ V; \ V_{DS} = 0 \ V; \ T_j = 25 \ ^{\circ}\text{C} \qquad - \qquad 100$ $16 \ V; \ V_{DS} = 0 \ V; \ T_j = 25 \ ^{\circ}\text{C} \qquad - \qquad 100$ $-16 \ V; \ V_{DS} = 0 \ V; \ T_j = 25 \ ^{\circ}\text{C}; \qquad - \qquad 100$ $10 \ V; \ I_D = 15 \ \text{A}; \ T_j = 25 \ ^{\circ}\text{C}; \qquad - \qquad 11 \qquad 13.1$	-	V	
V _{GS(th)}	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = -55 °C; Fig. 10	-	-	2.45	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 11; Fig. 10	1.3	1.7	2.15	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; Fig. 10	0.5	-	-	V
I _{DSS}	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	0.03	1	μA
	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA	
I _{GSS}	gate leakage current	V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 °C	-	- 100	nA	
		V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; Fig. 12	-	9.35	11.3	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; Fig. 12	-	11	13.1	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 175 °C; Fig. 12; Fig. 13	-	-	24.8	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 175 °C; Fig. 12; Fig. 13	-	-	28.8	mΩ
R _G	gate resistance	f = 1 MHz	-	1.86	-	Ω

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Dynamic cl	haracteristics		I			
Q _{G(tot)}	total gate charge	$I_{D} = 15 \text{ A}; V_{DS} = 30 \text{ V}; V_{GS} = 10 \text{ V};$ $T_{j} = 25 \text{ °C}; \underline{\text{Fig. 14}}; \underline{\text{Fig. 15}}$	-	37.2	-	nC
		I_D = 15 A; V_{DS} = 30 V; V_{GS} = 4.5 V;	-	16.6	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5	-	nC
Q _{GD}	gate-drain charge		-	5.1	-	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 15 A; V _{DS} = 30 V; T _j = 25 °C; <u>Fig. 14; Fig. 15</u>	-	2.75	-	V
C _{iss}	input capacitance	V_{DS} = 30 V; V_{GS} = 0 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 16</u>	-	2191	-	pF
C _{oss}	output capacitance	V_{DS} 30 V; V_{GS} = 0 V; f = 1 MHz; T _j = 25 °C; Fig. 16	-	199	-	pF
C _{rss}	reverse transfer capacitance	V_{DS} = 30 V; V_{GS} = 0 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 16</u>	-	111	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R _L = 2 Ω; V _{GS} = 4.5 V;	-	13.3	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	20.2	-	ns
t _{d(off)}	turn-off delay time		-	27.7	-	ns
t _f	fall time		-	15.5	-	ns
Source-dra	in diode					
V _{SD}	source-drain voltage	I _S = 15 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u>	-	0.84	1.2	V
t _{rr}	reverse recovery time	I _S = 15 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V;	-	20.7	-	ns
Q _r	recovered charge	V _{DS} = 30 V; T _j = 25 °C	-	15.7	-	nC

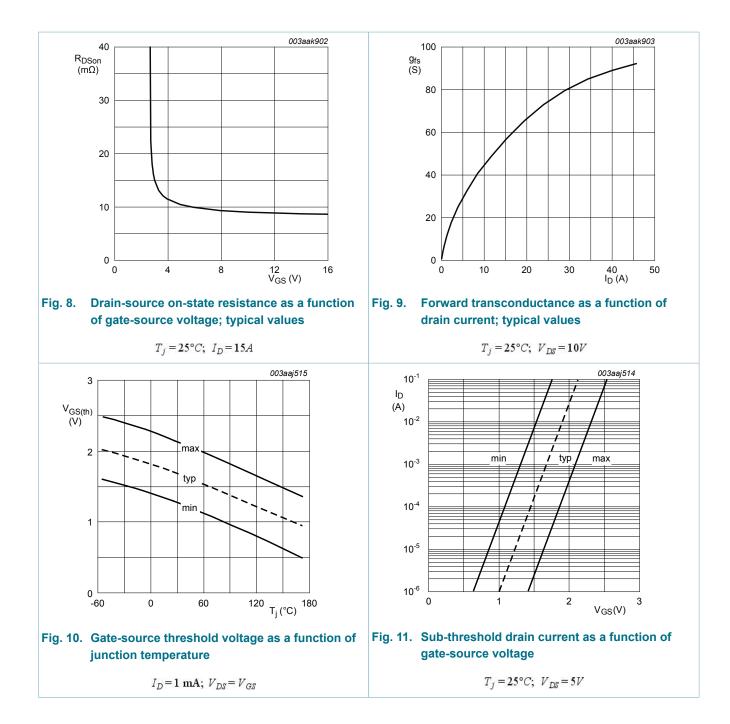






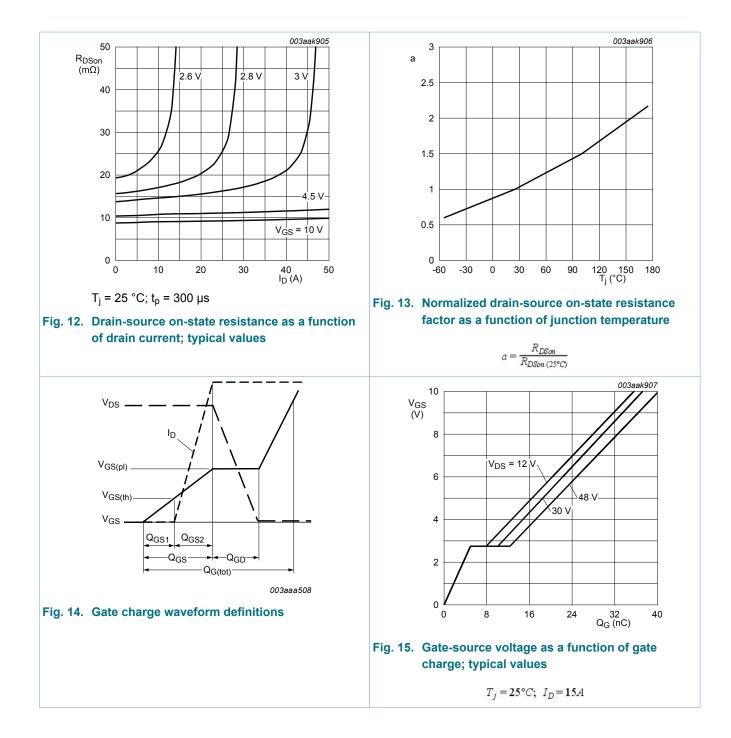


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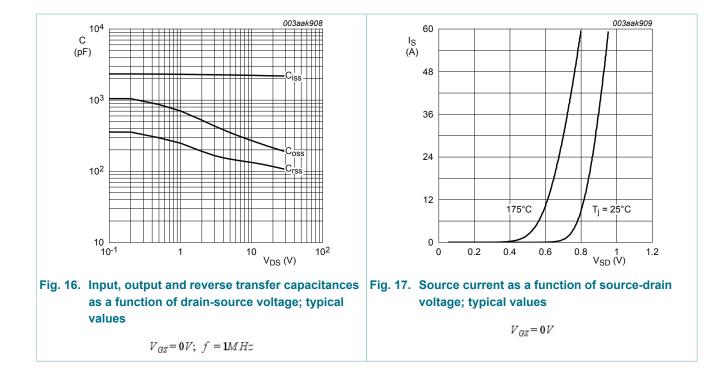
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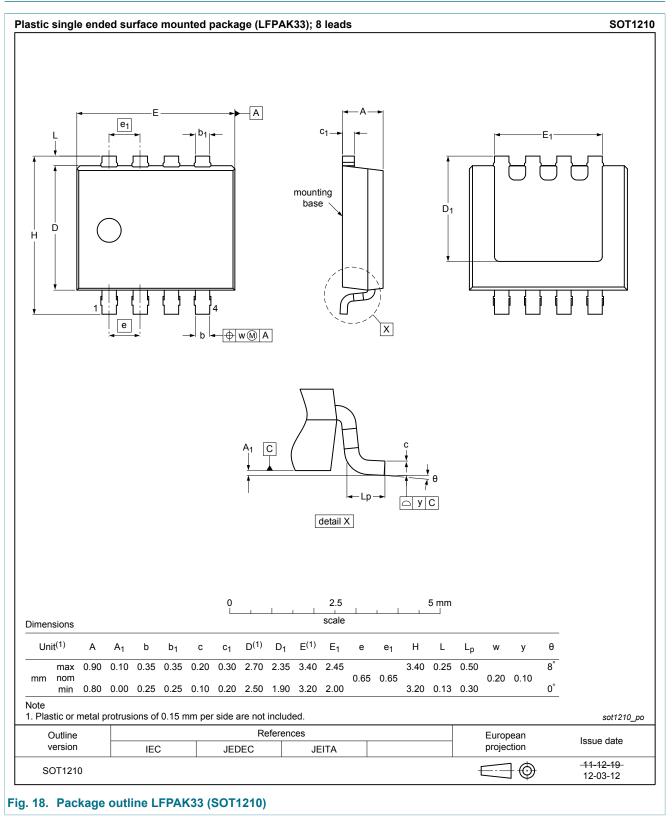
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11. Package outline



PSMN011-60ML

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12. Legal information

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